

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	100	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	8.3 6.7	А
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	54	Α
Avalanche Current (Note 8) L = 3mH			I _{AS}	7.5	Α
Avalanche Energy (Note 8) L = 3mH			E _{AS}	85	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	P _D	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	100	°C/W
Total Power Dissipation (Note 6)	P_D	1.67	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	75	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	12	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

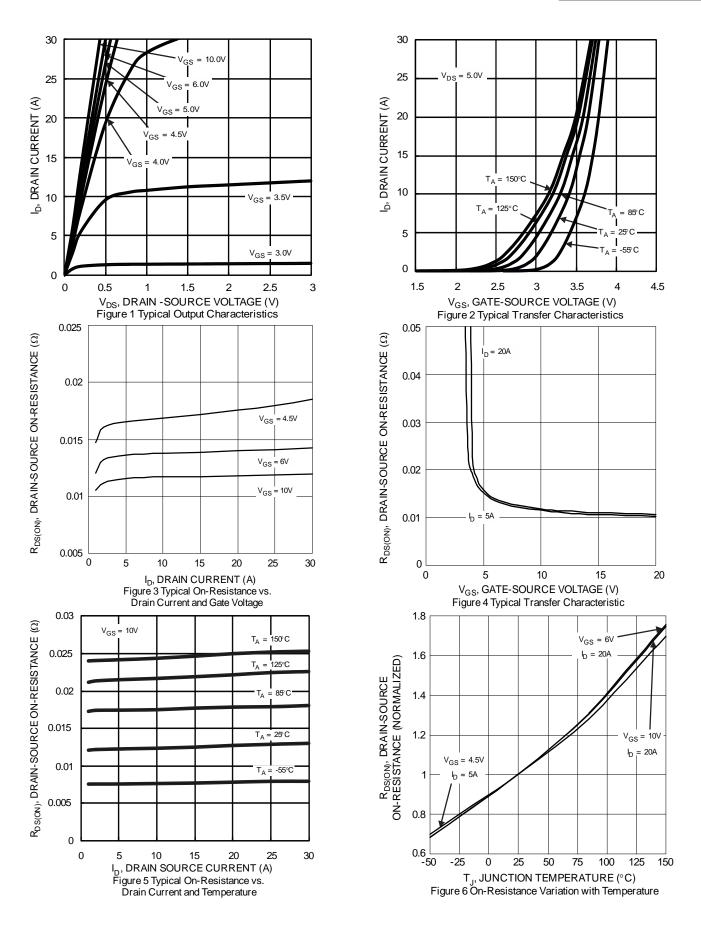
Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.4	2.3	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
			12	16	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	14.5	18		$V_{GS} = 6V, I_D = 20A$	
		-	17	25		$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	V_{SD}	_	0.9	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	1,871	_		$V_{DS} = 50V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		261	_	pF		
Reverse Transfer Capacitance	C _{RSS}	_	7	_			
Gate Resistance	R_{G}	_	0.75	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_G	_	33.3	_			
Gate-Source Charge	Q _{GS}	_	6.9	_	nC	$V_{DD} = 50V, I_D = 10A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q_{GD}	_	5.1	_			
Turn-On Delay Time	t _{D(ON)}	_	6.5	_			
Turn-On Rise Time	t _R	_	7	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_{D} = 10A, R_{G} = 6\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	19.7	_	ns		
Turn-Off Fall Time	t _F	_	8.1	_			
Reverse Recovery Time	t _{RR}	_	37.9	_	ns L 40A II/II 400A/		
Reverse Recovery Charge	Q_{RR}	-	51.9	_	nC	$I_F = 10A$, di/dt = 100A/ μ s	

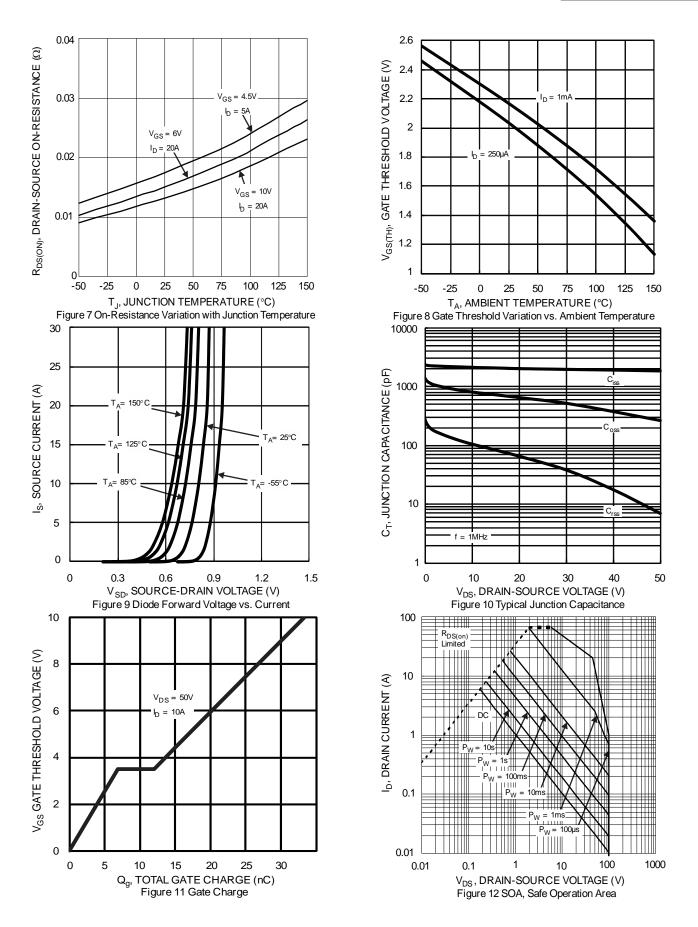
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 202 copper, with minimum recommended pa
Device mounted on FR-4 substrate PC board, 202 copper, with 1-inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

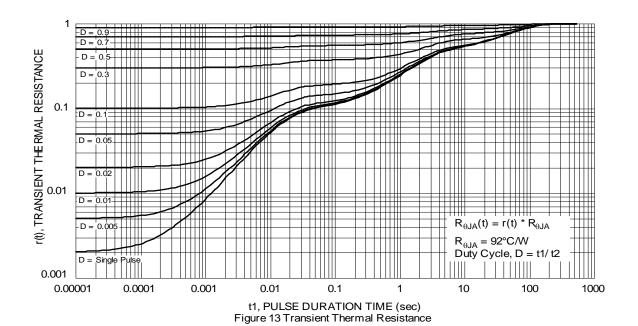










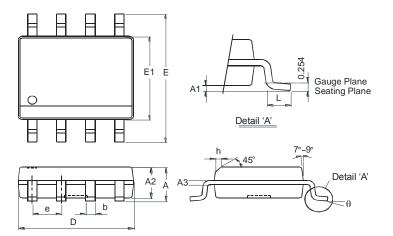




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

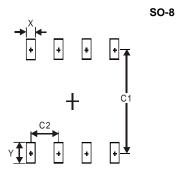




	SO-8		
Dim	Min	Max	
Α	-	1.75	
A1	0.10	0.20	
A2	1.30	1.50	
A3	0.15	0.25	
b	0.3	0.5	
D	4.85	4.95	
Е	5.90	6.10	
E1	3.85	3.95	
е	1.27 Typ		
h	-	0.35	
L	0.62	0.82	
θ	0°	8°	
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1 27



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